Preferred Device

Schottky Barrier Diodes

These Schottky barrier diodes are designed for high-speed switching applications, circuit protection, and voltage clamping. Extremely low forward voltage reduces conduction loss. Miniature surface mount package is excellent for hand-held and portable applications where space is limited.

Features

- Extremely Fast Switching Speed
- Low Forward Voltage 0.35 V (Typ) @ $I_F = 10 \text{ mA}$
- Pb-Free Package is Available

MAXIMUM RATINGS (T_J = 125°C unless otherwise noted)

Rating	Symbol	Value	Unit
Reverse Voltage	V _R	30	V

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (Note 1) $T_A = 25^{\circ}C$	PD	200	mW
Derate above 25°C		1.57	mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	635	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to 125	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

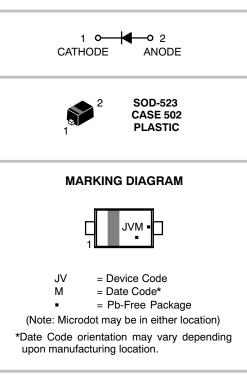
1. FR-4 Minimum Pad.



ON Semiconductor®

http://onsemi.com

30 VOLT SILICON HOT-CARRIER DETECTOR AND SWITCHING DIODES



ORDERING INFORMATION

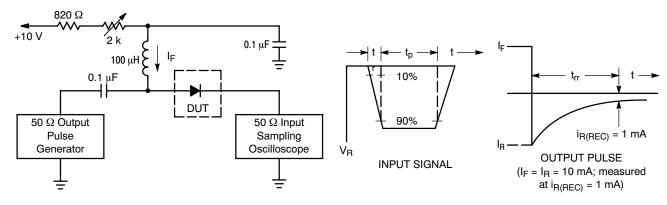
Device	Package	Shipping [†]
BAT54XV2T1	SOD-523	3000 / Tape & Reel
BAT54XV2T1G	SOD-523 (Pb-Free)	3000 / Tape & Reel
BAT54XV2T5G	SOD-523 (Pb-Free)	8000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

Characteristic	Symbol	Min	Тур	Мах	Unit
Reverse Breakdown Voltage $(I_R = 10 \ \mu A)$	V _{(BR)R}	30	-	-	V
Total Capacitance (V _R = 1.0 V, f = 1.0 MHz)	CT	-	7.6	10	pF
Reverse Leakage (V _R = 25 V)	۱ _R	-	0.5	2.0	μΑ
Forward Voltage (I _F = 0.1 mA)	V _F	-	0.22	0.24	V
Forward Voltage (I _F = 1.0 mA)	V _F	-	0.29	0.32	V
Forward Voltage (I _F = 10 mA)	V _F	-	0.35	0.40	V
Forward Voltage (I _F = 30 mA)	V _F	-	0.41	0.5	V
Forward Voltage (I _F = 100 mA)	V _F	-	0.52	0.8	V
Reverse Recovery Time ($I_F = I_R = 10 \text{ mA}, I_{R(REC)} = 1.0 \text{ mA}$) Figure 1	t _{rr}	-	-	5.0	ns
Forward Current (DC)	١ _F	-	-	200	mA
Repetitive Peak Forward Current	I _{FRM}	-	-	300	mA
Non-Repetitive Peak Forward Current (t < 1.0 s)	I _{FSM}	-	-	600	mA

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)



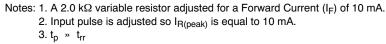
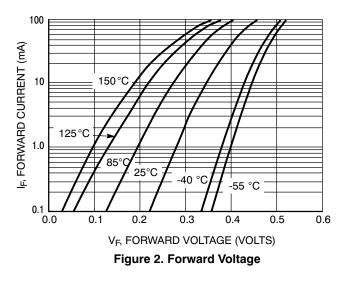


Figure 1. Recovery Time Equivalent Test Circuit



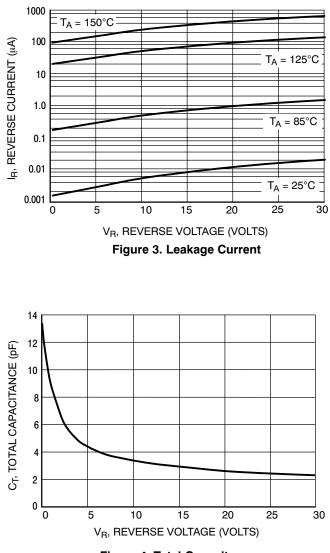
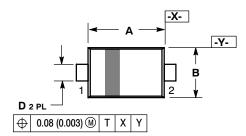
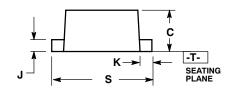


Figure 4. Total Capacitance

PACKAGE DIMENSIONS

SOD-523 CASE 502-01 ISSUE C



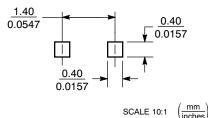


NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETER.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.10	1.20	1.30	0.043	0.047	0.051
В	0.70	0.80	0.90	0.028	0.032	0.035
С	0.50	0.60	0.70	0.020	0.024	0.028
D	0.25	0.30	0.35	0.010	0.012	0.014
ſ	0.07	0.14	0.20	0.0028	0.0055	0.0079
K	0.15	0.20	0.25	0.006	0.008	0.010
S	1.50	1.60	1.70	0.059	0.063	0.067

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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